

## Influence of grain size and micro-structure on battery performance of thin film cathodes for lithium-ion batteries

Influence of annealing temperature

940 nm ambient air t = 13.2 s

= 400°C

= 300°C

500

(XPS)

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normalized intensity [a.

Co2p<sub>3/2</sub>

laser structured

Co C

wave number [cm<sup>-1</sup>]

10 - 20 nm (as-deposited filn

crack formation occurs even at low tempe though film adhesion persists the crystallite sizes range from

about 100 nm (annealed at 600°C)

>1 µm (increased grain growth at 700°C)

Chemical surface composition

Co4

transformation to HT-LiCoO2 with increasing temperature

intensity [a.

Laser annealing

Influence of annealing time (Raman)

HT-LICoO (\*°95°cm\*1)

940 nm ambient a T = 600°C

132 s

= 13.2 s

5.3 s

2.6

0.13 s

500 600

wave number [cm<sup>-1</sup>

annealing time
the crystallite sizes range from 10 - 20 nm (as-deposited film)

Battery cycling

C/5 C/20

.

increasing charge current

theoretical capacity

transformation to HT-LiCoO<sub>2</sub> with increasing

about 100 nm (annealed for 13.2 s)

about 200 nm (annealed for 132 s)

ntensity [a. u.]

Analytics and battery cycling

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. nt air

HT-LiCoO<sub>2</sub> (482 cm<sup>-1</sup>)

(Raman)

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Motivation: Thin film electrodes are used to create high performance lithium ion batteries. Large surface area allows for high lithium diffusion and thereby high charging currents. Objective: Approach: Defined adjustment of thin film properties Combination of thin film deposition and selective laser processing

## Thin film deposition



The thin film deposition parameters have significant influence on film properties: • stoichiometry can be influenced by working gas pressure (with 10 Pa nearly stoichiometric  $LiCoO_2$  films

are created) substrate bias can control the thin film density, morphology and the texture. The crystalline orientation of the thin films can be adjusted → optimization of electrochemical properties.

## Laser patterning



Projekthaus e-drive

DAIMLER

grating and line patterns with minimum channel widths  $\sim 600 \text{ nm}$  high laser fluences (>2 J/cm²) lead to smooth ablation

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selective material ablation and re-deposition

lead to growth of surface structures • growth of cones (up to 8.4 µm) • small material loss (0% - 20%)



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"LIB-NANO"

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